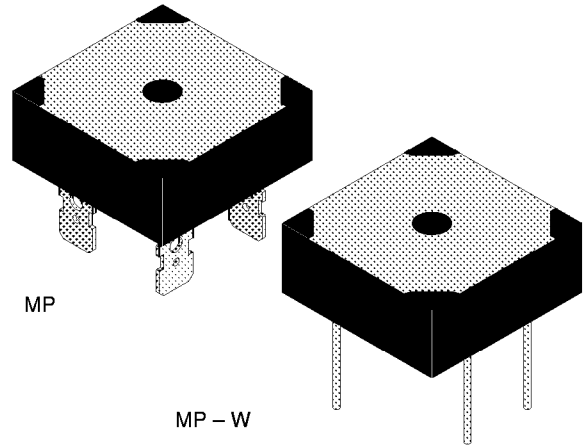




35A Bridge Rectifier

Features

- Diffused junction
- Low reverse leakage current
- Surge overload rating to 400A peak
- Low power loss, high efficiency
- Case to terminal isolation voltage 2500V
- UL Listed under recognized component index, file number E95060



14454

Absolute Maximum Ratings

$T_j = 25^\circ\text{C}$

| Parameter | Test Conditions | Type | Symbol | Value | Unit |
|--|------------------------|-----------|-----------------------------------|------------|------------------|
| Repetitive peak reverse voltage =Working peak reverse voltage =DC Blocking voltage | | MP35005/W | V_{RRM} $=V_{RWM}$ $=V_R$ | 50 | V |
| | | MP3501/W | | 100 | V |
| | | MP3502/W | | 200 | V |
| | | MP3505/W | | 400 | V |
| | | MP3506/W | | 600 | V |
| | | MP3508/W | | 800 | V |
| | | MP3510/W | | 1000 | V |
| Peak forward surge current | | | I_{FSM} | 400 | A |
| Average forward current | $T_C=55^\circ\text{C}$ | | I_{FAV} | 35 | A |
| Junction and storage temperature range | | | $T_j=T_{stg}$ | -65...+125 | $^\circ\text{C}$ |

Electrical Characteristics

$T_j = 25^\circ\text{C}$

| Parameter | Test Conditions | Type | Symbol | Min | Typ | Max | Unit |
|-------------------------------------|-----------------------------------|------|------------|-----|-----|-----|----------------------|
| Forward voltage | 17.5A DC | | V_F | | | 1.1 | V |
| Reverse current | $T_C=25^\circ\text{C}$ | | I_R | | | 10 | μA |
| | $T_C=100^\circ\text{C}$ | | I_R | | | 0.5 | mA |
| I^2t Rating for fusing | | | I^2t | | | 664 | A^2s |
| Diode capacitance | $V_R=4\text{V}$, $f=1\text{MHz}$ | | C_D | | 400 | | pF |
| Thermal resistance junction to case | mounted on heatsink | | R_{thJC} | | 3.8 | | K/W |



Characteristics ($T_j = 25^\circ\text{C}$ unless otherwise specified)

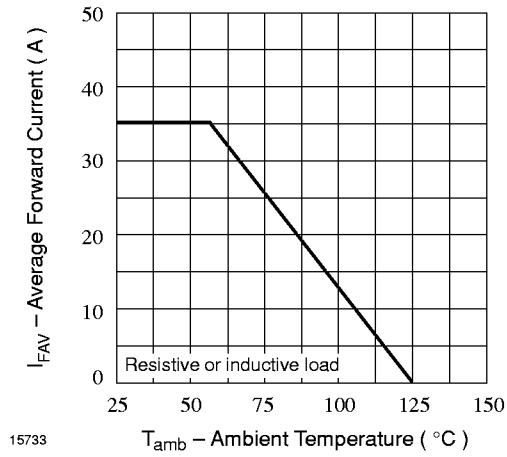


Figure 1. Max. Average Forward Current vs. Ambient Temperature

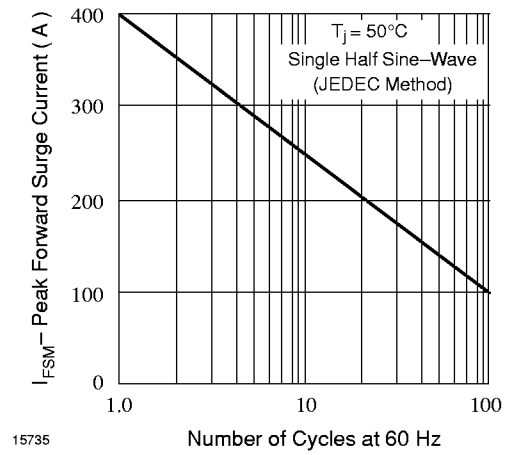


Figure 3. Max. Peak Forward Surge Current vs. Number of Cycles

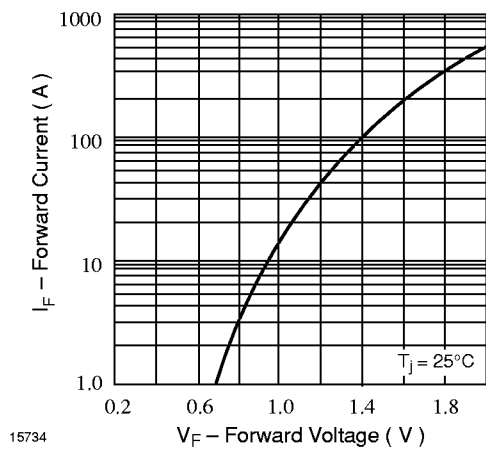


Figure 2. Typ. Forward Current vs. Forward Voltage

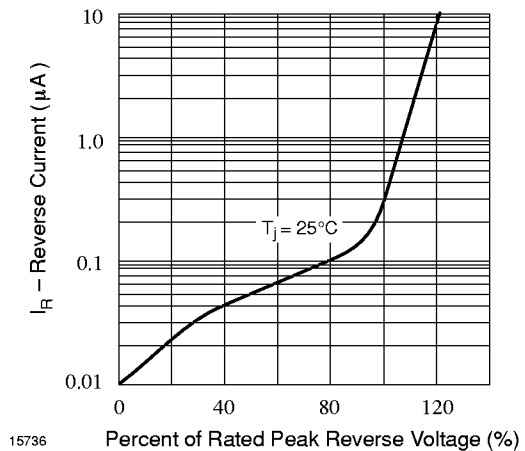
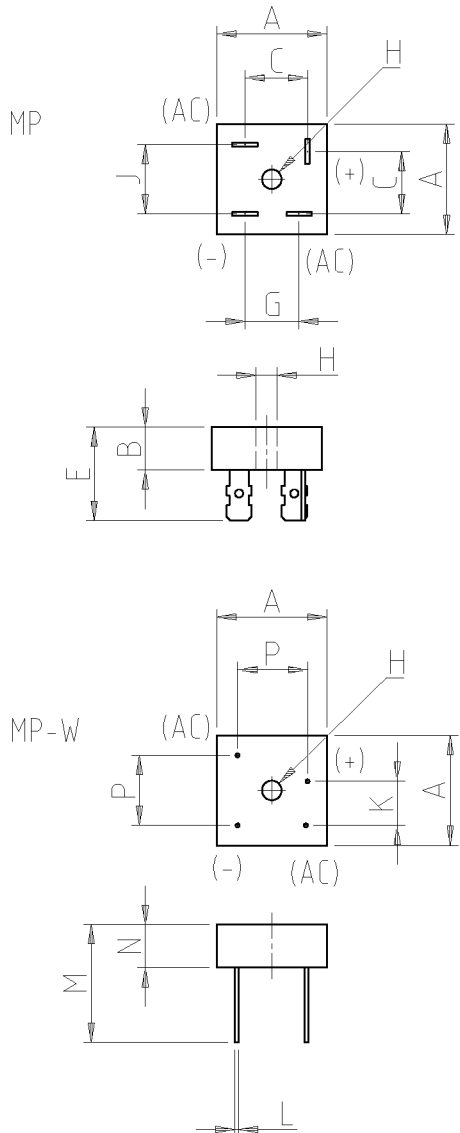


Figure 4. Typ. Reverse Current vs. Percent of Rated Peak Reverse Voltage

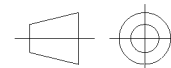


Dimensions in mm



| MP/MP-W | | |
|----------------------|-------------------------------------|-------|
| Dim | Min | Max |
| A | 28.40 | 28.70 |
| B | 10.97 | 11.23 |
| C | 15.70 | 16.70 |
| E | 22.86 | 25.40 |
| G | 13.50 | 14.50 |
| H | Hole for #10 screw ø5.08 Nominal | |
| J | 17.50 | 18.50 |
| K | 10.90 | 11.90 |
| L | ø0.97 | ø1.07 |
| M | 30.50 | - |
| N | 10.97 | 11.23 |
| P | 17.60 | 18.60 |
| All Dimensions in mm | | |

"W" Suffix Designates Wire Leads
 No Suffix Designates Faston Terminals



technical drawings
 according to DIN
 specifications

14480

Case: molded plastic with heatsink internally mounted in the bridge encapsulation
 Terminals: plated leads solderable per MIL–STD–202, method 208
 Polarity: symbols marked on case
 Approx. weight: MP 24 grams,
 MP–W 21 grams
 Mounting: through hole for #10 screw
 Mounting torque: 8.0 in–lbs maximum
 Mounting position: any
 Marking: type number



Ozone Depleting Substances Policy Statement

It is the policy of **Vishay Semiconductor GmbH** to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay-Telefunken products for any unintended or unauthorized application, the buyer shall indemnify Vishay-Telefunken against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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